Quad Array for ESD Protection

This quad monolithic silicon voltage suppressor is designed for applications requiring transient overvoltage protection capability. It is intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment, and other applications. Its quad junction common anode design protects four separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Specification Features

- SOT-553 Package Allows Four Separate Unidirectional Configurations
- Low Leakage < 1 µA @ 3 Volt for NZQA5V6XV5T1
- Breakdown Voltage: 5.6 Volt 6.8 Volt @ 1 mA
- ESD Protection Meeting IEC61000-4-2 Level 4

Mechanical Characteristics

- Void Free, Transfer-Molded, Thermosetting Plastic Case
- Corrosion Resistant Finish, Easily Solderable
- Package Designed for Optimal Automated Board Assembly
- Small Package Size for High Density Applications
- 100% Lead Free, MSL1 @ 260°C Reflow Temperature



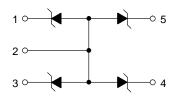
http://onsemi.com



MARKING DIAGRAM



xx = Device MarkingD = One Digit Date Code



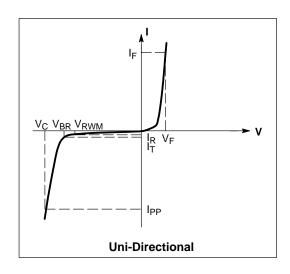
ORDERING INFORMATION

Device	Package	Shipping	
NZQA5V6XV5T1	SOT-553	4000/Tape & Reel	
NZQA6V2XV5T1	SOT-553	4000/Tape & Reel	
NZQA6V8XV5T1	SOT-553	4000/Tape & Reel	

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V_{BR}	Breakdown Voltage @ I _T
I _T	Test Current
ΘV _{BR}	Maximum Temperature Coefficient of V _{BR}
l _F	Forward Current
V _F	Forward Voltage @ I _F
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}
I _{ZK}	Reverse Current
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}



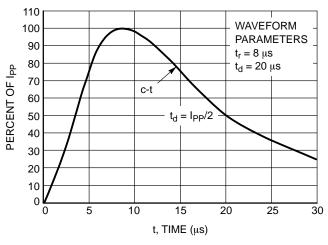
MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

	Characteristic	Symbol	Value	Unit
Peak Power Dissipation	on (8 X 20 μs @ T _A = 25°C) (Note 1)	P _{PK}	100	W
Steady State Power -	1 Diode (Note 2)	P _D	300	mW
Thermal Resistance J Above 25°C, Derate		$R_{ hetaJA}$	370 2.7	°C/W mW/°C
Maximum Junction Ter	mperature	T _{Jmax}	150	°C
Operating Junction an	d Storage Temperature Range	T _J T _{stg}	-55 to +150	°C
ESD Discharge	MIL STD 883C - Method 3015-6 IEC1000-4-2, Air Discharge IEC1000-4-2, Contact Discharge	V _{PP}	16 16 9	kV
Lead Solder Temperat	ture (10 seconds duration)	TL	260	°C

ELECTRICAL CHARACTERISTICS $(T_A = 25^{\circ}C)$

	Device		down Vo	_	Leakage Current		V _C Max @ Ipp		Typ Capacitance @ 0 V Bias (Note 3)	Max V _F
Device	Marking	Min	Nom	Max	V _{RWM}	I _{RWM} (μA)	V _C (V)	I _{PP} (A)	(pF)	(V)
NZQA5V6XV5T1	56	5.32	5.6	5.88	3.0	1.0	10.5	10	90	1.3
NZQA6V2XV5T1	62	5.89	6.2	6.51	4.0	0.5	11.5	9.0	80	1.3
NZQA6V8XV5T1	68	6.46	6.8	7.14	4.3	0.1	12.5	8.0	70	1.3

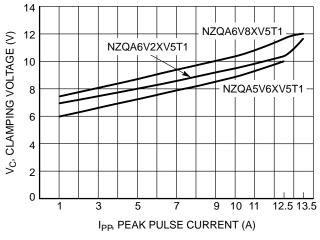
- Non-repetitive current per Figure 1.
 Only 1 diode under power. For all 4 diodes under power, P_D will be 25%. Mounted on FR-4 board with min pad.
 Capacitance of one diode at f = 1 MHz, V_R = 0 V, T_A = 25°C



% OF RATED POWER OR IPP T_A, AMBIENT TEMPERATURE (°C)

Figure 1. Pulse Waveform

Figure 2. Power Derating Curve



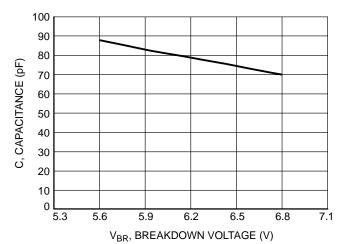
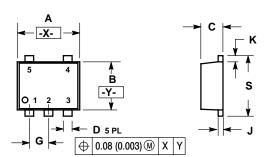


Figure 3. Clamping Voltage versus Peak Pulse Current

Figure 4. Typical Capacitance

PACKAGE DIMENSIONS

SOT-553, 5-LEAD CASE 463B-01 ISSUE O



NOTES:

MATERIAL.

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETERS
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE

	MILLIN	IETERS	INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	1.50	1.70	0.059	0.067		
В	1.10	1.30	0.043	0.051		
С	0.50	0.60	0.020	0.024		
D	0.17	0.27	0.007	0.011		
G	0.50	BSC	0.020 BSC			
J	0.08	0.18	0.003	0.007		
K	0.10	0.30	0.004	0.012		
S	1.50	1.70	0.059	0.067		

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